

Title (en)
METHOD OF FORMING A COLD CATHODE FLUORESCENT LAMP, THICK FILM ELECTRODE COMPOSITIONS USED THEREIN AND LAMPS AND LCD DEVICES FORMED THEREOF

Title (de)
VERFAHREN ZUR FORMUNG EINER FLUORESZIERENDEN KALTKATHODENLAMPE, DARIN VERWENDETE DICKFILMELEKTRODENZUSAMMENSETZUNGEN SOWIE DARAUS GEFORMTE LAMPEN UND LCD-VORRICHTUNGEN

Title (fr)
PROCÉDÉ DE FORMATION DE LAMPE FLUORESCENTE À CATHODE FROIDE, COMPOSITIONS D'ÉLECTRODES DE FILM ÉPAIS UTILISÉES DEDANS ET LAMPES ET PÉRIPHÉRIQUES LCD FORMÉS AINSI

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Abstract (en)
[origin: WO2008091673A2] The present invention relates to method(s) of fabricating a cold cathode fluorescence lamp (CCFL) utilizing thick film compositions. The CCFL of the present invention may be used in thin film transistor-liquid crystal display (TFT-LCD) applications and for providing a structure of the electrodes of used in TFT-LCD backlight units.

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